

## BD157/158/159

## **Low Power Fast Switching Output Stages**

For T.V Radio Audio Output Amplifiers



## **NPN Epitxial Silicon Transistor**

## Absolute Maximum Ratings $T_C=25^{\circ}C$ unless otherwise noted

Symbol	Paramet	er	Value	Units
V <sub>CBO</sub>	Collector-Base Voltage	: BD157	275	V
		: BD158	325	V
		: BD159	375	V
$V_{CEO}$	Collector-Emitter Voltage	: BD157	250	V
		: BD158	300	V
		: BD159	350	V
V <sub>EBO</sub>	Emitter-Base Voltage		5	V
I <sub>C</sub>	Collector Current (DC)		0.5	А
I <sub>CP</sub>	*Collector Current (Pulse)		1.0	Α
I <sub>B</sub>	Base Current		0.25	Α
P <sub>C</sub>	Collector Dissipation (T <sub>C</sub> =25°C)		20	W
T <sub>J</sub>	Junction Temperature		50	°C
T <sub>STG</sub>	Storage Temperature		- 65 ~ 150	°C

### Electrical Characteristics $T_C=25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV <sub>CEO</sub>	*Collector-Emitter Breakdown Voltage : BD157 : BD158	$I_C = 1mA$ , $I_B = 0$	250 300			V
	: BD159		350			V
I <sub>CBO</sub>	Collector Cut-off Current	.,				
	: BD157 : BD158 : BD159	$V_{CB} = 275V, I_{E} = 0$ $V_{CB} = 325V, I_{E} = 0$ $V_{CB} = 375V, I_{E} = 0$			100 100 100	μΑ μΑ μΑ
I <sub>EBO</sub>	Emitter Cut-off Current	$V_{EB} = 5V, I_{C} = 0$			100	μΑ
h <sub>FE</sub>	* DC Current Gain	$V_{CE} = 10V, I_{C} = 50mA$	30		240	

<sup>\*</sup> Pulse Test: PW=300µs, duty Cycle=1.5% Pulsed

# **Typical Characteristics**

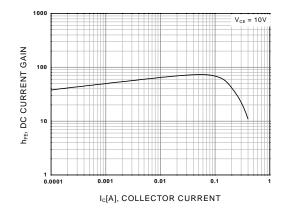


Figure 1. DC current Gain

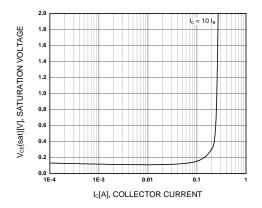


Figure 2. Collector-Emitter Saturation Voltage

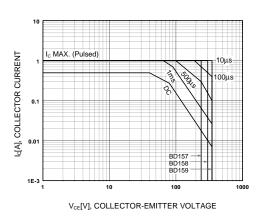


Figure 3. Safe Operating Area

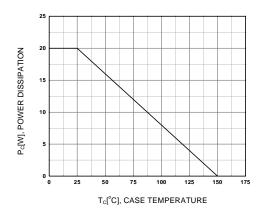
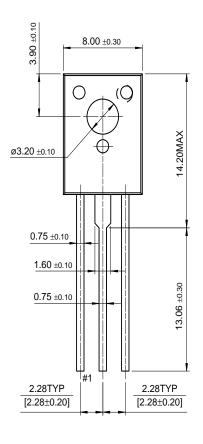
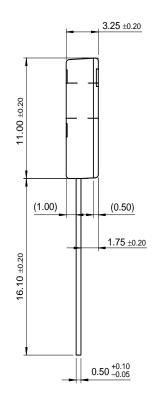


Figure 4. Power Derating

# **Package Demensions**

TO-126







Dimensions in Millimeters

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